

Features

### Quad, Low-Voltage, SPST Analog Switches with Enable

### General Description

The MAX4536/MAX4537/MAX4538 are quad, low-voltage, single-pole/single-throw (SPST) analog switches with a common enable pin. They are pin compatible with the industry-standard 74HC4316. The MAX4536 has four normally open (NO) switches, and the MAX4537 has four normally closed (NC) switches. The MAX4538 has two NO switches and two NC switches.

These switches operate from a +2V to +12V single supply, or from  $\pm 2V$  to  $\pm 6V$  dual supplies. On-resistance (200 $\Omega$  max) is matched between switches to  $4\Omega$  (max) and is flat (10 $\Omega$  max) over the specified signal range. Each switch can handle rail-to-rail analog signals. The off-leakage current is only 1nA at +25°C and 10nA at +85°C.

All digital inputs have 0.8V to 2.4V logic thresholds, ensuring TTL/CMOS-logic compatibility when using a single +5V supply or dual ±5V supplies.

### \_Applications

Battery-Operated Equipment

Low-Voltage Data Acquisition

Test Equipment

**Avionics** 

Portable Equipment

Audio-Signal Routing

Networking

### ♦ Pin Compatible with 74HC4316

- ◆ ±2.0V to ±6V Dual Supplies +2.0V to +12V Single Supply
- Four Separately Controlled SPST Switches with Common Enable
- ♦ 100Ω Signal Paths with Dual ±5V Supplies 200Ω Signal Paths with Single +4.5V Supply
- ◆ Rail-to-Rail Signal Handling
- ton and toff = 100ns and 80ns at ±4.5V Supply
- ♦ Less than 1µW Power Consumption
- >2kV ESD Protection per Method 3015.7
- ◆ TTL/CMOS-Compatible Inputs
- Small Packages: PDIP, QSOP, Narrow SO

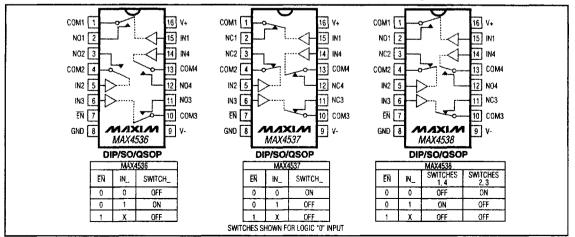
### Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4536CPE	0°C to +70°C	16 Plastic DIP
MAX4536CSE	0°C to +70°C	16 Narrow SO
MAX4536CEE	0°C to +70°C	16 QSOP
MAX4536C/D	0°C to +70°C	Dice*
MAX4536EPE	-40°C to +85°C	16 Plastic DIP
MAX4536ESE	-40°C to +85°C	16 Narrow SO
MAX4536EEE	-40°C to +85°C	16 QSOP

Ordering information continued at end of data sheet.

\*Contact factory for availability.

### Pin Configurations/Functional Diagrams/Truth Tables



MIXIM

Maxim Integrated Products

### **ABSOLUTE MAXIMUM RATINGS**

Voltages Referenced to GND	
V+,	0.3V to +13.0V
V	13.0V to +0.3V
V+ to V	0.3V to +13.0V
All Other Pins (Note 1)	(V0.3V) to $(V++0.3V)$
Continuous Current into Any Termina	1±10mA
Peak Current into Any Terminal	
(pulsed at 1ms,10% duty cycle)	±20mA
ESD per Method 3015.7	>2000V

Continuous Power Dissipation (TA = +70°C) (Note	2)
Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Narrow SO (derate 8.70mW/°C above +70°C)	
QSOP (derate 8.00mW/°C above +70°C)	800mW
Operating Temperature Ranges	
MAX453_C_ E	.0°C to +70°C
MAX453_E_ E	40°C to +85°C
Storage Temperature Range65	
Lead Temperature (soldering, 10sec)	+300°C

Note 1: Signals on NC\_, NO\_, COM\_, EN, or IN\_ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Note 2: All leads are soldered or welded to PC boards.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ELECTRICAL CHARACTERISTICS-±5V Dual Supplies

 $(V+=4.5V \text{ to } 5.5V, V-=-4.5V \text{ to } -5.5V, V_{INH}=2.4V, V_{INL}=0.8V, V_{\overline{EN}}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, unless otherwise noted. Typical values are at <math>T_A=+25^{\circ}C.)$ 

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS		
ANALOG SWITCH									
Analog Signal Range	VCOM_i VNO_i VNC	(Note 4)	C, E	٧-		V+	V		
COM_NO_, COM_NC_ On-Resistance	RON	V+ = 4.5V, V- = -4.5V, VCOM = 3.5V, ICOM = 1mA	+25°C C, E		55	100 125	Ω		
Or Friedistance		VEON_ = 0.0V, ICON_ = 1777					1		
COM_NO_, COM_NC_	ADam	V+ = 4.5V, V- = -4.5V. +25	+25°C		1	4	Ω		
On-Resistance Match Between Channels (Note 5)	AHON	VCOM_ = 3.5V, ICOM_ = 1mA		ΔRON VCOM_ = 3.5V, ICOM_ = 1mA		<del>, , , , , , , , , , , , , , , , , , , </del>		6	] <sup>11</sup>
COM_NO_, COM_NC_	η	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	+25°C		4	10	Ω		
On-Resistance Flatness (Note 6)	RFLAT(ON)		C, E			15	7 12		
NO_, NC_ Off-Leakage Current	INO_(OFF).	V+ = 5.5V, V- = -5.5V,	+25°C	-1	0.01	1	nA		
(Note 7)	INC_(OFF)	V <sub>COM</sub> _ = ±4.5V, V <sub>N</sub> _ = ∓4.5V	C, E	-10		10	TIA TIA		
COM Off-Leakage Current		V+ = 5.5V, V- = -5.5V,	+25°C	-1	0.01	1	nA		
(Note 7)	ICOM_(OFF)	COM_(OFF) $V_{COM} = \pm 4.5V, V_{N} = \pm 4.5V$ C, I	C, E	-10		10	7 11A		
COM On-Leakage Current		V+ = 5.5V, V- = -5.5V,	+25°C	-2	0.01	2	nA		
(Note 7)	COM_(ON)	VCOM_ = ±4.5V, VN_ = ±4.5V		-20		20	7 "		
LOGIC INPUT	·								
EN, IN_Input Logic Threshold High	VINH		C, E		1.4	2.4	V		
EN, IN_Input Logic Threshold Low	VINL		C, E	0.8	1.4		V		
EN, IN_ Input Current Logic High or Low	INH_, INL_	V <sub>IN</sub> _ = 0.8V or 2.4V	C, E	-1	0.03	1	μA		

### ELECTRICAL CHARACTERISTICS—±5V Dual Supplies (continued)

 $(V+=4.5V \text{ to } 5.5V, V-=-4.5V \text{ to } -5.5V, V_{INH}=2.4V, V_{INL}=0.8V, V_{EN}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } T_A=+25^{\circ}C.)$ 

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
SWITCH DYNAMIC CHARACTERI	STICS						<del></del>
Turn-On Time	ton	$V_{COM} = \pm 3V, V_{+} = 4.5V,$	+25°C		35	100	T
Tail PON Time	ION	V- = -4.5V (Figure 1)	C, E			125	ns
Turn-Off Time	toff	$V_{COM} = \pm 3V, V + = 4.5V,$	+25°C		15	50	rıs
Toni-on time	IUFF	V- = -4.5V (Figure 1)	C, E			60	118
Break-Before-Make Time Delay (MAX4538 Only)	MBBJ	VCOM_ = ±3V, V+ = 5.5V, V- = -5.5V (Figure 2)	+25°C	5	15		rs
Charge Injection (Figure 3)	Q	$C_L = 1.0 nF, V_{NO} = 0V, R_S = 0\Omega$	+25°C		1	5	pC
NO_, NC_ Off-Capacitance (Figure 6)	C <sub>N_(OFF)</sub>	V <sub>NO</sub> _ = GND, f = 1MHz	+25°C		2		pF
COM_ Off-Capacitance (Figure 6)	CCOM_(OFF)	VCOM_ = GND, f = 1MHz	+25°C		2		pF
COM_ On-Capacitance (Figure 7)	CCOM_(ON)	VCOM_ = VNO_ = GND, f = 1MHz	+25°C		6		pF
Off-Isolation (Note 8, Figure 4)	Viso	$R_L = 50\Omega$ , $C_L = 15pF$ , $V_{N_\perp} = 1V_{RMS}$ , $f = 1MHz$	+25°C		-65		dB
Channel-to-Channel Crosstalk (Note 9, Figure 5)	Vcт	$R_L = 50\Omega$ , $C_L = 15pF$ , $V_{N_\perp} = 1V_{RMS}$ , $f = 1MHz$	+25°C		-75		dB
POWER SUPPLY							
Power-Supply Range	V+, V-		C, E	-6		6	V
V+ Supply Current	1+	V+ = 5.5V, all V <sub>IN</sub> = 0V or V+	+25°C	-1	0.05	1	μА
v+ Supply Culteri	'*	V1 = 0.0 V, all VIN_ = 0 V 0/ V+	C, E	-10		10	] "
V- Supply Current	1-	V- = -5.5V	+25°C	-1	0 05	1	μA
V. Supply Outlett	<u>'</u>		C, E	-10		10	μ,τ

### **ELECTRICAL CHARACTERISTICS—+5V Single Supply**

 $(V+=4.5V \text{ to } 5.5V, V-=0V, V_{INH}=2.4V, V_{INL}=0.8V, V_{\overline{EN}}=0.8V, T_A=T_{MIN} \text{ to } T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A=+25^{\circ}C.)$ 

Analog Signal Range   VCOM_VNO_VNO_VNO_VNO_VNO_VNO_VNO_VNO_VNO_VNO	PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
VNO_ VNO_ VNO_ VNO_ VNO_ VNO_ VNO_ VNO_	ANALOG SWITCH	L		_				<del></del>
On-Resistance         RON         ICOM_ = 1mA         C, E         225         Ω           COMNO_, COMNC_ On-Resistance Match Between Channels (Note 5)         ΔRON         V+ = 4.5V, V <sub>COM_</sub> = 3.5V, ICOM_ = 1mA         +25°C         2 8         Ω           NO_, NC_Off-Leakage Current (Notes 7, 10)         INO_(OFF), INC_(OFF)         V+ = 5.5V, V <sub>COM_</sub> = 1V. 4.5V, V <sub>N</sub> = +4.5V, 1V         +25°C         -1 0.01 1 C.E         nA           COM_Off-Leakage Current (Notes 7, 10)         ICOM_(OFF)         V+ = 5.5V, V <sub>COM_</sub> = 1V. 4.5V, V <sub>N</sub> = +4.5V, 1V         +25°C         -1 0.01 1 C.E         nA           COM_On-Leakage Current (Note 7, 10)         ICOM_(ON)         V+ = 5.5V, V <sub>COM_</sub> = 1V. 4.5V, V <sub>N</sub> = +4.5V, 1V         +25°C         -2 0.01 2 C.E         nA           COM_On-Leakage Current (Note 7, 10)         ICOM_(ON)         V+ = 5.5V, V <sub>COM_</sub> = 1V. 4.5V, V <sub>N</sub> = +4.5V, 1V         +25°C         -2 0.01 2 C.E         nA           LOGIC INPUT         ICOM_(ON)         V+ = 5.5V, V <sub>COM</sub> = 1V. 4.5V, V <sub>N</sub> = 0.8V or 2.4V         C.E         1.4         2.4         V           EN, INInput Logic Threshold Low         I <sub>INH</sub> I <sub>INL</sub> V <sub>IN</sub> = 0.8V or 2.4V         C.E         -1 0.03 1         µA           SWITCH DYNAMIC CHARACTERISTICS         Instruction of the complex of t	Analog Signal Range		(Note 4)	C, E	0		V+	٧
COM_ = IMA   C, E   225   COM_ = NO_, COM_ = NO_   NO_, COM_ = NO_   NO_, COM_ = IMA   V+ = 4.5V, VCOM_ = 3.5V,   CoM_ = 1 MA   V+ = 4.5V, VCOM_ = 3.5V,   C E   10	COMNO_, COMNC_	Ron		+25°C		90	200	
On-Resistance Match Between Channels (Note 5)         ΔRON         V = 4.5V, VCOM_ = 3.5V.   COM_ = 1.00           C E         10         Ω           NO_, NC_Off-Leakage Current (Notes 7, 10)         INO_(OFF), INC_(OFF), INC_(OFF)         V + = 5.5V, VCOM_ = 1V. 4.5V, VCOM_ =	On-Resistance	TON	ICOM_ = 1mA	C, E			225	32
Commons (Note 3)   Commons (Note 4)   Commons (Note 3)   Commons (Note 3)   Commons (Note 3)   Commons (Note 4)   Commons (N	COMNO_, COMNC_ On-Resistance Match Between	ΔRon		+25°C		2	8	Ω
(Notes 7, 10)	Channels (Note 5)		ICOM_ = IMA	C, E			10	
(Notes 7, 10)	NO_, NC_ Off-Leakage Current	NO_(OFF),	V+ = 5.5V, V <sub>COM</sub> = 1V. 4.5V,	+25°C	-1	0.01	1	
COM_(OFF)   COM_(OFF)   VN_ = +4.5V, 1V   C, E   -10   10   10   10   10   10   10   1	(Notes 7, 10)	INC_(OFF)	V <sub>N_</sub> = +4.5V, 1V	C, E	-10		10	
COM_ On-Leakage Current (Note 7, 10)   COM_ (ON)   V+ = 5.5V, VCOM_ = 1V, 4.5V,   C, E   -10   10   10   10   10   10   10   1	COM_ Off-Leakage Current	loos (orm	V+ = 5.5V, V <sub>COM</sub> = 1V, 4.5V,	+25°C	-1	0.01	1	
COM_(ON)   V+ = 5.5V, VCOM_ = 1V, 4.5V,   C, E   20   20   10	(Notes 7, 10)	I COM_(OFF)	V <sub>N</sub> _ = +4.5V, 1V	C, E	-10		10	10
C, E   -20   20   20   20   20   20   20   2	COM_ On-Leakage Current		V+ = 5.5V, V <sub>COM</sub> _ = 1V, 4.5V,	+25°C	-2	0.01	2	nA
EN, IN_ Input Logic Threshold High         V <sub>INL</sub> C, E         1.4         2.4         V           EN, IN_ Input Logic Threshold Low         V <sub>INL</sub> C, E         0.8         1.4         V           EN, IN_ Input Current Logic         I <sub>INH_</sub> , I <sub>INL</sub> V <sub>IN_</sub> = 0.8V or 2.4V         C, E         -1         0.03         1         μA           SWITCH DYNAMIC CHARACTERISTICS           Turn-On Time         ton         V <sub>COM_</sub> = 3V, V + = 4.5V (Figure 1)         +25°C         50         100         ns           Turn-Off Time         toff         V <sub>COM_</sub> = 3V, V + = 4.5V (Figure 1)         +25°C         80         ns           Break-Before-Make Time Delay         t <sub>BBM</sub> MAX4538, V <sub>COM_</sub> = 3V, V + = 5.5V (Figure 2)         +25°C         5         25         ns           Charge Injection (Figure 3) (Note 4)         Q         C <sub>L</sub> = 1.0nF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω         +25°C         1         5         pC           POWER SUPPLY	(Note 7, 10)	(COM_(ON)		C, E	-20		20	
EN, IN_ Input Logic Threshold Low         VINL         C, E         0.8         1.4         V           EN, IN_ Input Current Logic High or Low         I <sub>INH_</sub> , I <sub>INL_</sub> VIN_ = 0.8V or 2.4V         C, E         -1         0.03         1         μA           SWITCH DYNAMIC CHARACTERISTICS           Turn-On Time         toN         VCOM_ = 3V, V+ = 4.5V (Figure 1)         +25°C         50         100         ns           Turn-Off Time         toFF         VCOM_ = 3V, V+ = 4.5V (Figure 1)         +25°C         80         ns           Break-Before-Make Time Delay         tbBM         MAX4538, VCOM_ = 3V, V+ = 4.5V (Figure 2)         +25°C         5         25         ns           Charge Injection (Figure 3) (Note 4)         Q         CL = 1.0nF, VNO = 0V, Rs = 0Ω         +25°C         1         5         pC           POWER SUPPLY	LOGIC INPUT							
EN, IN_ Input Current Logic High or Low    InH_, InL_   VIN_ = 0.8V or 2.4V   C. E	EN, IN_ Input Logic Threshold High	VINH		C, E		1.4	2.4	V
High of Low         INH_, INL_         VIN_ = 0.89 of 2.49         C. E         -1         0.03         μA           SWITCH DYNAMIC CHARACTERISTICS           Turn-On Time         toN         VCOM_ = 3V, V+ = 4.5V (Figure 1)         +25°C         50         100         ns           Turn-Off Time         toFF         VCOM_ = 3V, V+ = 4.5V (Figure 1)         +25°C         80         ns           Break-Before-Make Time Delay         tbBM         MAX4538, VCOM_ = 3V, V+ = 5.5V (Figure 2)         +25°C         5         25         ns           Charge Injection (Figure 3) (Note 4)         Q         CL = 1.0nF, VNO = 0V, Rs = 0Ω         +25°C         1         5         pC           POWER SUPPLY	EN, IN_ Input Logic Threshold Low	VINL		C, E	0.8	1.4		V
Turn-On Time  toN  VCOM_ = 3V, V+ = 4.5V (Figure 1)  torn-Off Time  toff  VCOM_ = 3V, V+ = 4.5V (Figure 1)  toff  VCOM_ = 3V, V+ = 4.5V (Figure 1)  toff  VCOM_ = 3V, V+ = 4.5V (Figure 1)  toff  VCOM_ = 3V, V+ = 4.5V (Figure 1)  c. E  100  ns  MAX4538, VCOM_ = 3V, V+ = 5.5V (Figure 2)  table Page Injection (Figure 3) (Note 4)  Q  CL = 1.0nF, VNO = 0V, Rs = 0Ω  +25°C  50  100  ns  RC  RC  FOR  POWER SUPPLY  V+ = 5.5V all Vin = 0V or V+  +25°C  -1  0.05  1  UA	EN, IN_ Input Current Logic High or Low	INH_, INL_	V <sub>IN</sub> _ = 0.8V or 2.4V	C. E	-1	0.03	1	μA
Turn-On Time         toN         (Figure 1)         C, E         20         125         ns           Turn-Off Time         toFF         VCOM_ = 3V, V+ = 4.5V (Figure 1)         +25°C         80         ns           Break-Before-Make Time Delay         tbBM         MAX4538, VCOM_ = 3V, V+ = 5.5V (Figure 2)         +25°C         5         25         ns           Charge Injection (Figure 3) (Note 4)         Q         CL = 1.0nF, VNO = 0V, Rs = 0Ω         +25°C         1         5         pC           POWER SUPPLY	SWITCH DYNAMIC CHARACTERIS	STICS		,				1, 4,
C   C   C   C   C   C   C   C   C   C	Turn On Time	tou	V <sub>COM</sub> <sub>_</sub> = 3V, V+ = 4.5V	+25°C		50	100	
Turn-Off Time         toff         (Figure 1)         C. E         100         ns           Break-Before-Make Time Delay         t <sub>BBM</sub> MAX4538, V <sub>COM</sub> = 3V, V <sub>+</sub> = 5.5V (Figure 2)         +25°C         5         25         ns           Charge Injection (Figure 3) (Note 4)         Q         C <sub>L</sub> = 1.0nF, V <sub>NO</sub> = 0V, R <sub>S</sub> = 0Ω         +25°C         1         5         pC           POWER SUPPLY           V <sub>+</sub> = 5 5V all V <sub>IN</sub> = 0V or V <sub>+</sub> +25°C         -1         0.05         1         UA	Turi-On Time	ION	(Figure 1)	C, E		20	125	7 115
C   C   C   C   C   C   C   C   C   C	Turn Off Time	tore	VCOM_ = 3V, V+ = 4.5V	+25°C			80	
V+ = 5.5V (Figure 2)   V+ = 5.5V (Figure 2	turn-Off time	LOFF	(Figure 1)	C. E			100	115
POWER SUPPLY  V+ = 5.5V all Vin = 0V or V+	Break-Before-Make Time Delay	tвам		+25°C	5	25		ns
V+ Supply Current	Charge Injection (Figure 3) (Note 4)	Q	$C_L = 1.0$ nF, $V_{NO} = 0$ V, $R_S = 0$ $\Omega$	+25°C		1	5	pC
$V_{+}$ Supply Current $V_{+} = 5.5V$ all $V_{1N} = 0V$ or $V_{+}$	POWER SUPPLY							.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
v+ Supply Current	V. Sanada Carrant	1.	V 5 5V 0HV(v 0V 05V)	+25°C	-1	0.05	1	
	v+ Supply Current	1+	V+ = 5.5V, all VIN_ = UV of V+	C, E	-10		10	PΑ

### **ELECTRICAL CHARACTERISTICS—+3V Single Supply**

 $(V+=2.7V \text{ to } 3.6V, V-=0V, V_{\text{INH}}=2.0V, V_{\text{INL}}=0.5V, V_{\overline{\text{EN}}}=0.5V, T_{\text{A}}=T_{\text{MIN}} \text{ to } T_{\text{MAX}}, \text{ unless otherwise noted.}$ Typical values are at  $T_{\text{A}}=+25^{\circ}\text{C}$ .)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
ANALOG SWITCH		<u> </u>					
Analog Signal Range	VCOM_, VNO_, VNC	(Note 4)	C, E	0		V+	V
COMNO_, COMNC_ On-Resistance	Ron	V+ = 2.7V, V <sub>COM</sub> _ = 1.5V, I <sub>COM</sub> _ = 0.1mA	+25°C C, E		210	500 600	Ω
LOGIC INPUT		· · · · · · · · · · · · · · · · · · ·					<del></del>
EN, IN_Input Logic Threshold High	VINH		C, E		0.9	2.0	V
EN, IN_ Input Logic Threshold Low	VINL		C, E	0.5	0.9		V
EN, IN_ Input Current Logic High or Low	INH_ INL_	V <sub>IN</sub> _ = 0.8V or 2.4V	C, E	-1	0.03	1	μА
SWITCH DYNAMIC CHARACTERIS	STICS (Note 4	1)					
Turn-On Time	ton	VCOM_ = 1.5V, V+ = 2.7V	+25°C		80	250	no
turn-on time	ton	(Figure 1)	C, E			300	ns
Turn-Off Time		V <sub>COM</sub> <sub>_</sub> = 1.5V, V+ = 2.7V	+25°C		40	100	ns
Turr-Oil Time	tOFF	(Figure 1)	C, E			120	7 "
Break-Before-Make Time Delay	<sup>t</sup> BBM	MAX4538, V <sub>COM</sub> = 1.5V, V+ = 3.6V (Figure 2)	+25°C	10	40		ns
Charge Injection (Figure 3)	Q	$C_L = 1.0$ nF, $V_{NO} = 0$ V, $R_S = 0$ Ω	+25°C			3	pC
POWER SUPPLY							
V+ Supply Current	1+	V+ = 3.6V, all V <sub>IN</sub> = 0V or V+	+25°C	-1	0.05	1	μA
у- опрыу синен	17	V = - 0.0V, all V <sub>HV</sub> = - 0V OI V +	C, E	-10		10	] "

Note 3: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 4: Guaranteed by design.

Note 5:  $\Delta Ron = \Delta Ron(MAX) - \Delta Ron(MIN)$ .

**Note 6:** Resistance flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog-signal range.

Note 7: Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at  $T_A = +25$ °C.

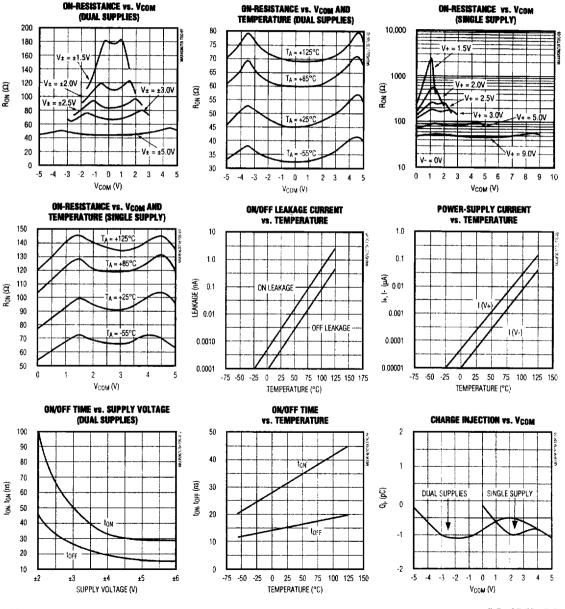
Note 8: Off-isolation = 20log 10 [VCOM / (VNC or VNO\_)], VCOM = output, VNC\_ or VNO\_ = input to off switch.

Note 9: Between any two switches.

Note 10: Leakage testing for single-supply operation is guaranteed by testing with dual supplies.

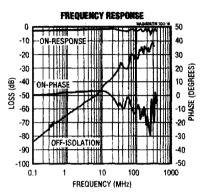
### Typical Operating Characteristics

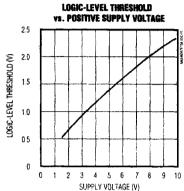
 $(V+=+5V, V-=-5V \text{ GND}=0V, T_A=+25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

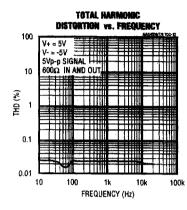


### Typical Operating Characteristics (continued)

 $(V+ = +5V, V- = -5V GND = 0V, T_A = +25^{\circ}C, unless otherwise noted.)$ 







### Pin Description

PIN	NAME	FUNCTION
1, 4, 10, 13	COM1-COM4	Analog Switch Common* Terminals
2, 3, 11, 12	NO1-NO4, or NC1-NC4	Analog Switch Normally Open* or Normally Closed* Terminals (see <i>Truth Tables</i> )
5, 6, 14, 15	IN1-IN4	Logic-Control Digital Inputs. Control each switch (see <i>Truth Tables</i> ), except when EN is high.
7	EN	Disable Logic Input. Connect logic high to EN to disable (open) all switches.
8	GND	Ground. Connect to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
9	V-	Negative Analog Supply-Voltage Input. Connect V- to GND for single-supply operation.
16	V+	Positive Analog and Digital Supply-Voltage Input. Internally connected to substrate.

<sup>\*</sup>NO\_NC\_ and COM\_ pins are identical and interchangeable. Either may be considered as an input or an output; signals pass equally well in either direction.

### \_Applications Information Power-Supply Considerations

#### Overview

The MAX4536/MAX4537/MAX4538 construction is typical of most CMOS analog switches. These devices have three supply pins: V+, V-, and GND. V+ and V- drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog-signal pin, and both V+ and V-. One of these diodes conducts if any analog signal exceeds V+ or V-. These reverse-biased ESD diodes leak during normal operation, forming the only current drawn from V+ or V-

Virtually all the analog leakage current is through the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages vary as the signal varies. The difference in the two diode leakages from the signal path to the V+ and V- pins constitutes the analog-signal path leakage current. All analog leakage current flows to the supply terminals, not to the other switch terminal. This explains how both sides of a given switch can show leakage currents of either the same or opposite polarity.

There is no connection between the analog-signal paths and GND. The analog-signal paths consist of an N-channel and P-channel MOSFET with their sources and drains paralleled and their gates driven out of phase to V+ and V- by the logic-level translators.

V+ and GND power the internal logic and logic-level translators and set the input logic thresholds. The logic-level translators convert the logic levels to switched V+ and V- signals to drive the analog switches' gates. This drive signal is the only connection between the logic supplies and the analog supplies. V+, and V- have ESD-protection diodes to GND. The logic-level inputs have ESD protection to V+ and to V-.

Increasing V- has no effect on the logic-level thresholds, but it does increase the drive to the P-channel switches, reducing their on-resistance. V- also sets the negative limit of the analog-signal voltage.

The logic-level thresholds are CMOS/TTL-compatible when V+ is +5V. The threshold increases slightly as V+ is raised. When V+ reaches +12V, the level threshold is about 3.1V, above the TTL output high-level minimum of 2.8V, but still compatible with CMOS outputs.

### **Bipolar Supplies**

The MAX4536/MAX4537/MAX4538 operate with bipolar supplies between ±2.0V and ±6V. The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the absolute maximum rating of 13.0V. Do not connect the MAX4536/MAX4537/MAX4538's V+ to +3V and then connect the logic-level input pins to TTL logic-level signals. TTL logic-level outputs in excess of the absolute maximum ratings can damage the part and/or external circuits.

**CAUTION:** The absolute maximum V+ to V- differential voltage is 13.0V. Typical ±6V or +12V supplies with ±10% tolerances can be as high as 13.2V. This voltage can damage the MAX4536/MAX4537/MAX4538. Even ±5% tolerance supplies may have overshoot or noise spikes that exceed 13.0V.

#### Single Supplies

The MAX4536/MAX4537/MAX4538 operate from single supplies between +2.0V and +12V when V- is connected to GND. All of the bipolar precautions must be observed.

#### **High-Frequency Performance**

In  $50\Omega$  systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on-response has several minor peaks that are highly layout dependent. The problem with high-frequency operation is not in turning the switch on, but in turning it off. The off-state switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off-isolation is about -44dB in  $50\Omega$  systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also make off-isolation worse. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is due entirely to capacitive coupling.

### Test Circuits/Timing Diagrams

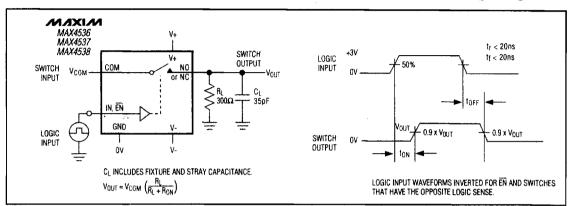


Figure 1. Switching Time

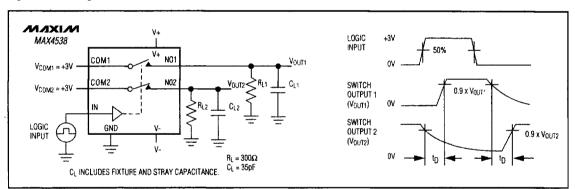


Figure 2. Break-Before-Make Interval (MAX4538 only)

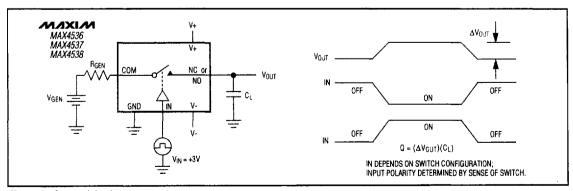


Figure 3. Charge Injection

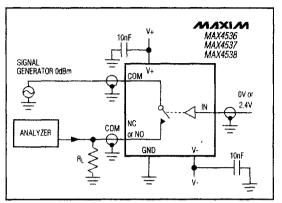


Figure 4. Off Isolation

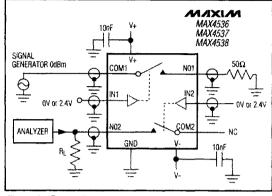


Figure 5. Crosstalk

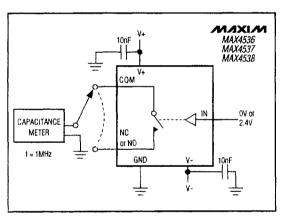


Figure 6. Channel-Off Capacitance

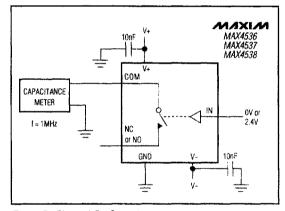


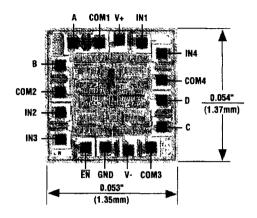
Figure 7. Channel-On Capacitance

### \_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX4537CPE	0°C to +70°C	16 Plastic DIP
MAX4537CSE	0°C to +70°C	16 Narrow SO
MAX4537CEE	0°C to +70°C	16 QSOP
MAX4537C/D	0°C to +70°C	Dice*
MAX4537EPE	-40°C to +85°C	16 Plastic DIP
MAX4537ESE	-40°C to +85°C	16 Narrow SO
MAX4537EEE	-40°C to +85°C	16 QSOP
MAX4538CPE	0°C to +70°C	16 Plastic DIP
MAX4538CSE	0°C to +70°C	16 Narrow SO
MAX4538CEE	0°C to +70°C	16 QSOP
MAX4538C/D	0°C to +70°C	Dice*
MAX4538EPE	-40°C to +85°C	16 Plastic DIP
MAX4538ESE	-40°C to +85°C	16 Narrow SO
MAX4538EEE	-40°C to +85°C	16 QSOP

<sup>\*</sup>Contact factory for availability.

### Chip Topography



MA	(4536	MAX4537		MAX	(4538
PIN	NAME	PIN	PIN NAME PI		NAME
A	NO1	Α	NC1	Α	NO1
В	NO2	В	NC2	В	NC2
С	NO3	С	NC3	С	NC3
D	NO4	D	NC4	D	NO4

TRANSISTOR COUNT: 121

SUBSTRATE IS INTERNALLY CONNECTED TO V+